



**ALPHA & OMEGA**  
SEMICONDUCTOR

# ***AOS Semiconductor Product Reliability Report***

**AOD460/AOD460L, rev C**

**Plastic Encapsulated Device**

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This AOS product reliability report summarizes the qualification result for AOD460. Accelerated environmental tests are performed on a specific sample size, and then followed by electrical test at end point. Review of final electrical test result confirms that AOD460 passes AOS quality and reliability requirements. The released product will be categorized by the process family and be monitored on a quarterly basis for continuously improving the product quality.

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### I. Product Description:

The AOD460 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications. Standard Product AOD460 is Pb-free (meets ROHS & Sony 259 specifications). AOD460L is a Green Product ordering option. AOD460 and AOD460L are electrically identical.

Absolute Maximum Ratings $T_A=25^\circ\text{C}$ unless otherwise noted				
Parameter		Symbol	Maximum	Units
Drain-Source Voltage		$V_{DS}$	25	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$T_A=25^\circ\text{C}$	$I_D$	25	A
	$T_A=100^\circ\text{C}$		25	
Pulsed Drain Current		$I_{DM}$	70	
Avalanche Current		$I_{AR}$	20	A
Repetitive avalanche energy 0.1mH <sup>C</sup>		$E_{AR}$	20	mJ
Power Dissipation	$T_A=25^\circ\text{C}$	$P_D$	30	W
	$T_A=100^\circ\text{C}$		15	
Power Dissipation	$T_A=25^\circ\text{C}$	$P_{DSM}$	2.5	W
	$T_A=100^\circ\text{C}$		1.6	
Junction and Storage Temperature Range		$T_J, T_{STG}$	-55 to 175	$^\circ\text{C}$

Thermal Characteristics					
Parameter		Symbol	Typ	Max	Units
Maximum Junction-to-Ambient	$T \leq 10\text{s}$	$R_{\theta JA}$	15	20	$^\circ\text{C/W}$
	Steady-State		50	60	$^\circ\text{C/W}$
Maximum Junction-to-Lead	Steady-State	$R_{\theta JL}$	4	7.5	$^\circ\text{C/W}$

## II. Die / Package Information:

	<b>AOD460</b>	<b>AOD460L (Green Compound)</b>
<b>Process</b>	Standard sub-micron low voltage N channel process	Standard sub-micron low voltage N channel process
<b>Package Type</b>	3 leads TO252	3 leads TO252
<b>Lead Frame</b>	Copper with Ni pad	Copper with Ni pad
<b>Die Attach</b>	Soft solder	Soft solder
<b>Bond wire</b>	Al 5&12mils	Al 5&12mils
<b>Mold Material</b>	Epoxy resin with silica filler	Epoxy resin with silica filler
<b>Filler % (Spherical/Flake)</b>	90/10	100/0
<b>Flammability Rating</b>	UL-94 V-0	UL-94 V-0
<b>Backside Metallization</b>	Ti / Ni / Ag	Ti / Ni / Ag
<b>Moisture Level</b>	Up to Level 1 *	Up to Level 1 *

**Note \*** based on info provided by assembler and mold compound supplier

## III. Result of Reliability Stress for AOD460 (Standard) & AOD460L (Green)

Test Item	Test Condition	Time Point	Lot Attribution	Total Sample size	Number of Failures
Solder Reflow Precondition	Standard: 1hr PCT+3 cycle reflow@260°C Green: 168hr 85°C /85%RH +3 cycles reflow@260°C	0hr	Standard: 47 lots Green: 5 lots	8140pcs	0
HTGB	Temp = 150°C , Vgs=100% of Vgsmax	168 / 500 hrs  1000 hrs	1 lot  (Note A*)	82pcs  77+5 pcs / lot	0
HTRB	Temp = 150°C , Vds=80% of Vdsmax	168 / 500 hrs  1000 hrs	1 lot  (Note A*)	82pcs  77+5 pcs / lot	0
HAST	130 +/- 2°C , 85%RH, 33.3 psi, Vgs = 80% of Vgs max	100 hrs	Standard: 47 lots Green: 4 lots  (Note B**)	2805pcs  50+5 pcs / lot	0
Pressure Pot	121°C , 15+/-1 PSIG, RH=100%	96 hrs	Standard: 44 lots Green: 4 lots  (Note B**)	2640pcs  50+5 pcs / lot	0
Temperature Cycle	-65°C to 150°C , air to air, 0.5hr per cycle	250 / 500 cycles	Standard: 44 lots Green: 5 lots  (Note B**)	2695pcs  50+5 pcs / lot	0

### III. Result of Reliability Stress for AOD460 (Standard) & AOD460L (Green) Continues

<b>DPA</b>	<b>Internal Vision Cross-section X-ray</b>	<b>NA</b>	<b>5 5 5</b>	<b>5 5 5</b>	<b>0</b>
<b>CSAM</b>		<b>NA</b>	<b>5</b>	<b>5</b>	<b>0</b>
<b>Bond Integrity</b>	<b>Room Temp 150°C bake 150°C bake</b>	<b>0hr 250hr 500hr</b>	<b>40 40 40</b>	<b>40 wires 40 wires 40 wires</b>	<b>0</b>
<b>Solderability</b>	<b>230°C</b>	<b>5 sec</b>	<b>15</b>	<b>15 leads</b>	<b>0</b>

**Note A:** The HTGB and HTRB reliability data presents total of available AOD460 and AOD460L burn-in data up to the published date.

**Note B:** The pressure pot, temperature cycle and HAST reliability data for AOD460 and AOD460L comes from the AOS generic package qualification data.

### IV. Reliability Evaluation

**FIT rate (per billion): 43**

**MTTF = 2654 years**

In general, 500 hrs of HTGB, 150 deg C accelerated stress testing is equivalent to 15 years of lifetime at 55 deg C operating conditions (by applying the Arrhenius equation with an activation energy of 0.7eV and 60% of upper confidence level on the failure rate calculation). AOS reliability group also routinely monitors the product reliability up to 1000 hr at and performs the necessary failure analysis on the units failed for reliability test(s).

The presentation of FIT rate for the individual product reliability is restricted by the actual burn-in sample size of the selected product (AOD460). Failure Rate Determination is based on JEDEC Standard JESD 85. FIT means one failure per billion hours.

$$\text{Failure Rate} = \text{Chi}^2 \times 10^9 / [2 (N) (H) (Af)] = 1.83 \times 10^9 / [2 (164) (500) (258)] = 43$$

$$\text{MTTF} = 10^9 / \text{FIT} = 2.3 \times 10^7 \text{hrs} = 2654 \text{ years}$$

**Chi<sup>2</sup>** = Chi Squared Distribution, determined by the number of failures and confidence interval

**N** = Total Number of units from HTRB and HTGB tests

**H** = Duration of HTRB/HTGB testing

**Af** = Acceleration Factor from Test to Use Conditions (Ea = 0.7eV and Tuse = 55°C)

$$\text{Acceleration Factor [Af]} = \text{Exp} [Ea / k (1/Tj u - 1/Tj s)]$$

**Acceleration Factor ratio list:**

	<b>55 deg C</b>	<b>70 deg C</b>	<b>85 deg C</b>	<b>100 deg C</b>	<b>115 deg C</b>	<b>130 deg C</b>	<b>150 deg C</b>
<b>Af</b>	<b>258</b>	<b>87</b>	<b>32</b>	<b>13</b>	<b>5.64</b>	<b>2.59</b>	<b>1</b>

**Tj s** = Stressed junction temperature in degree (Kelvin), K = C+273.16

**Tj u** = The use junction temperature in degree (Kelvin), K = C+273.16

**k** = Boltzmann's constant, 8.617164 X 10<sup>-5</sup>eV / K

## V. Quality Assurance Information

Acceptable Quality Level for outgoing inspection: **0.1%** for electrical and visual.

Guaranteed Outgoing Defect Rate: **< 25 ppm**

Quality Sample Plan: conform to **Mil-Std-105D**